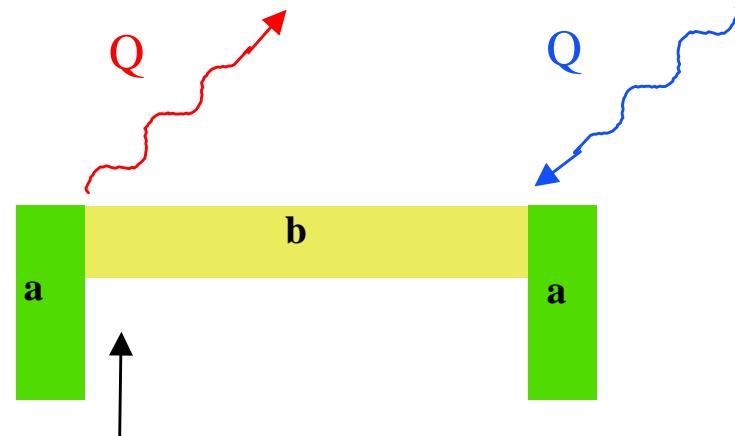


Peltier, Seebeck and Thompson Effects

(V)

(1934)

Peltier: $\pi_{ab} = \pi_a - \pi_b = \frac{Q}{I}$

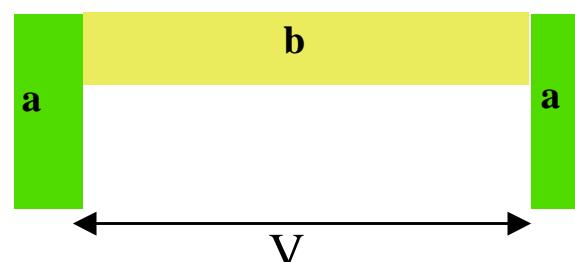


(VK⁻¹)

(1954)

Thomson relation: $\begin{cases} \pi = S \cdot T \\ \mu = \frac{dS}{dT} T \end{cases}$

T₁ T₂



(VK⁻¹)

(1921)

Seebeck: $S = \frac{\Delta V}{\Delta T}$

material a

material b

Thermoelectric power conversion-basic data

Seebeck Coefficient
Temperature
El. resistivity
Thermal Conductivity

$$ZT = \frac{\alpha^2 T}{\rho \lambda}$$

Figure of merit

ZT Determines Efficiency

Carnot efficiency

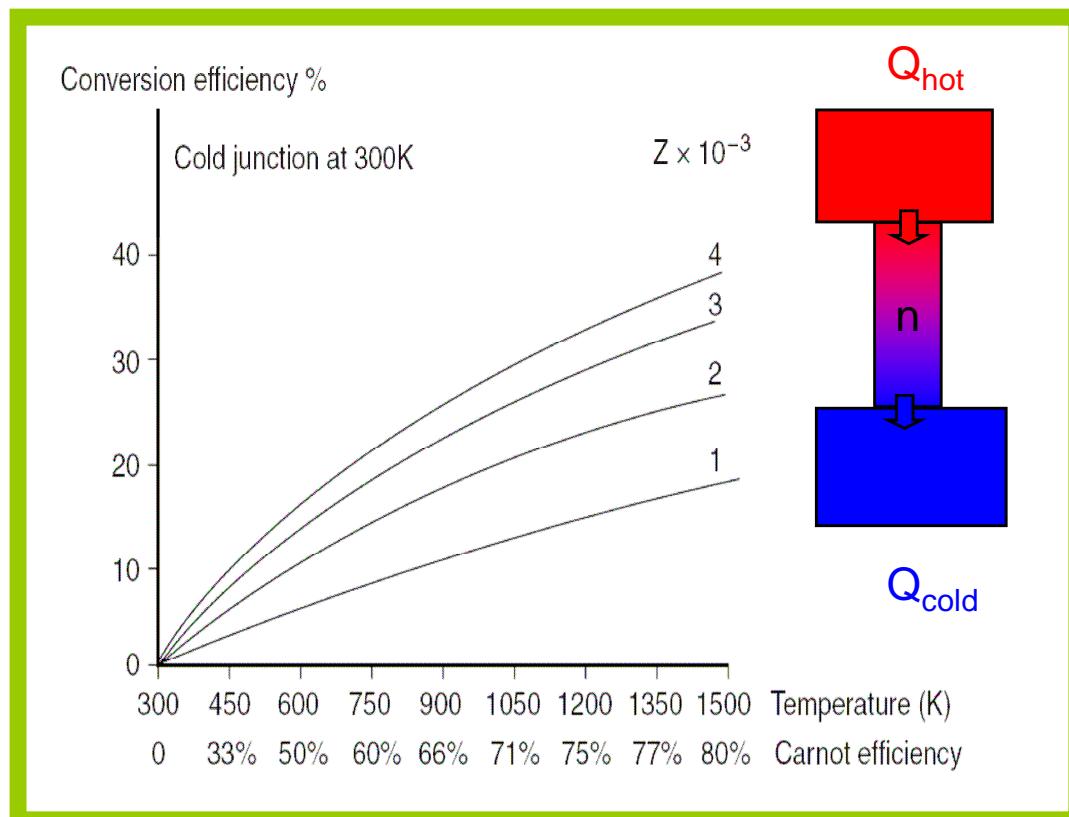
Thermoelectric efficiency

Electricity Generation

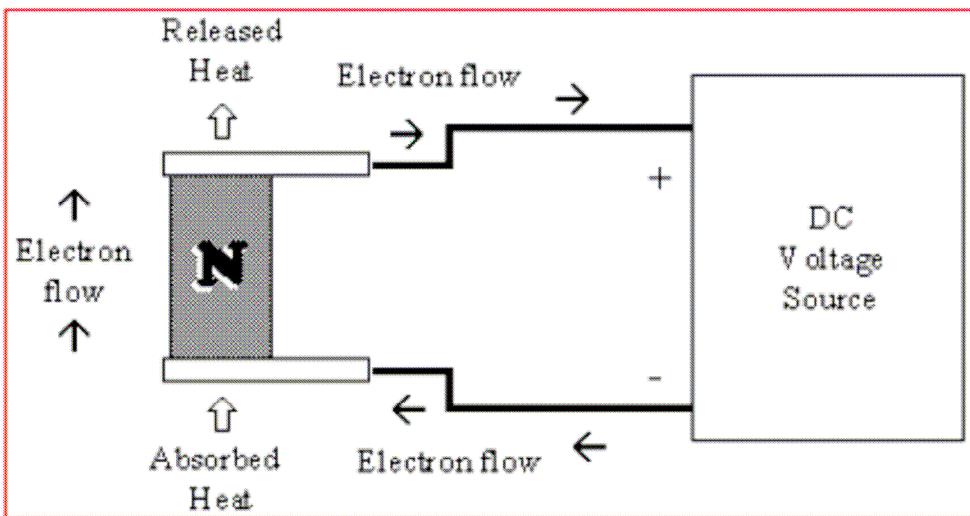
$$\eta = \frac{T_H - T_C}{T_H} \frac{\sqrt{1+ZT} - 1}{\sqrt{1+ZT} + \frac{T_C}{T_H}}$$

Temperature Cooling

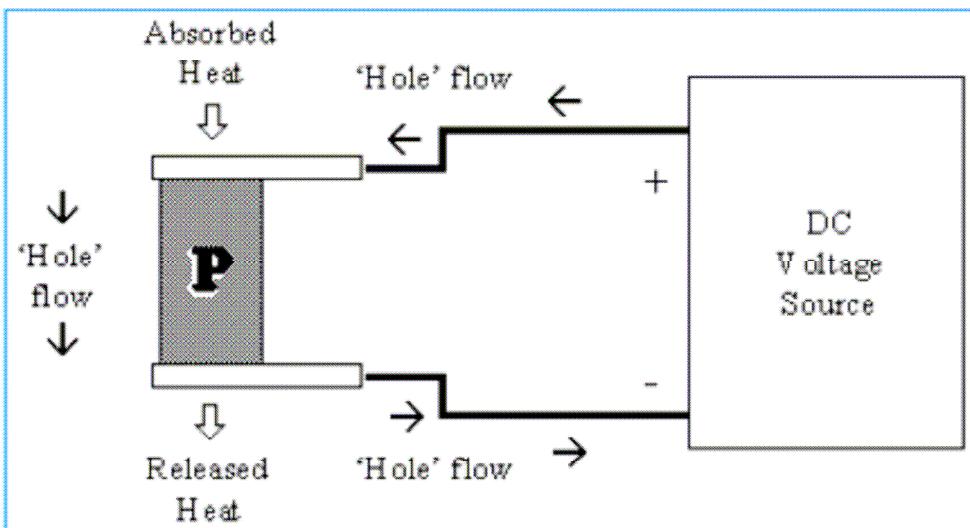
$$(C.O.P.)_{\max} = \frac{T_C}{T_H - T_C} \frac{\sqrt{1+ZT} - \frac{T_H}{T_C}}{\sqrt{1+ZT} + 1}$$



Thermoelectric cooler -basic data



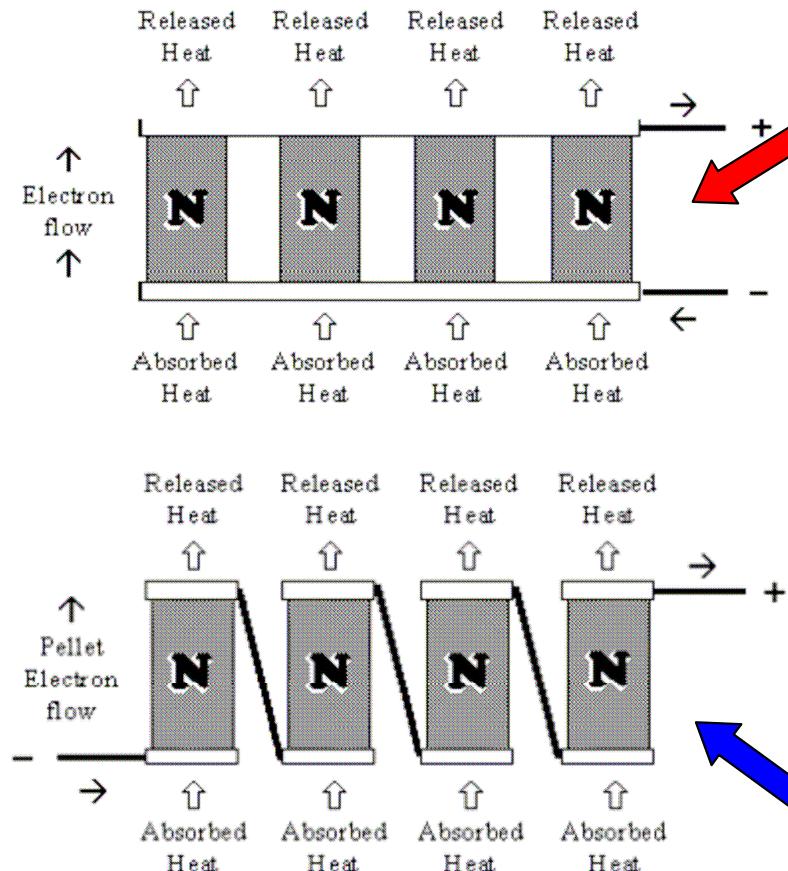
n- type semiconductor



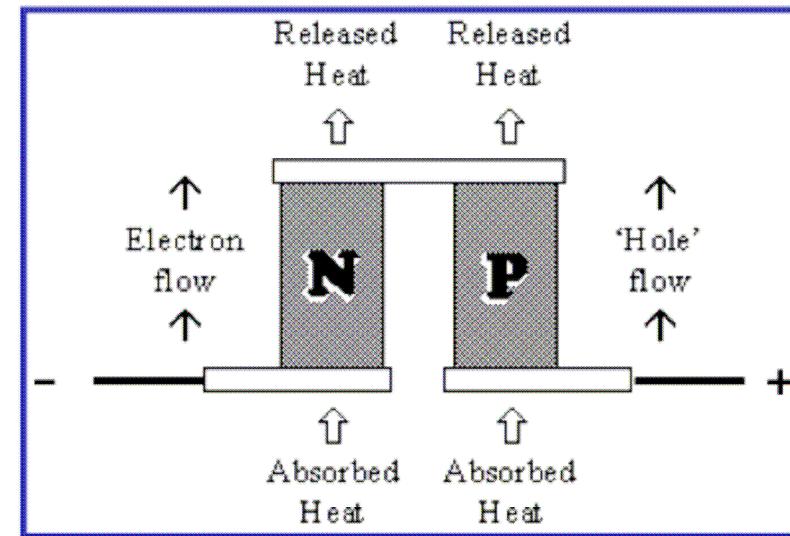
p- type semiconductor

Thermoelectric converter battery -basic data

One type of material
Thermally, electrically parallel



High current – low voltage

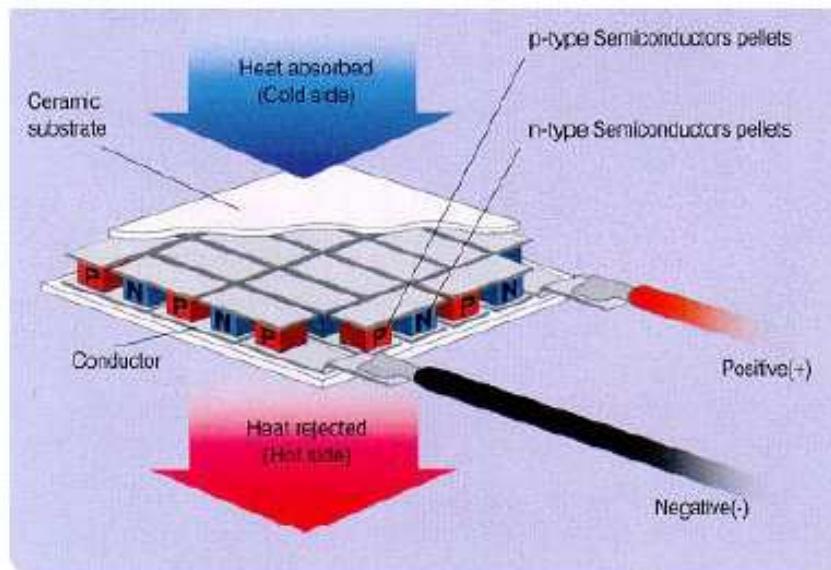
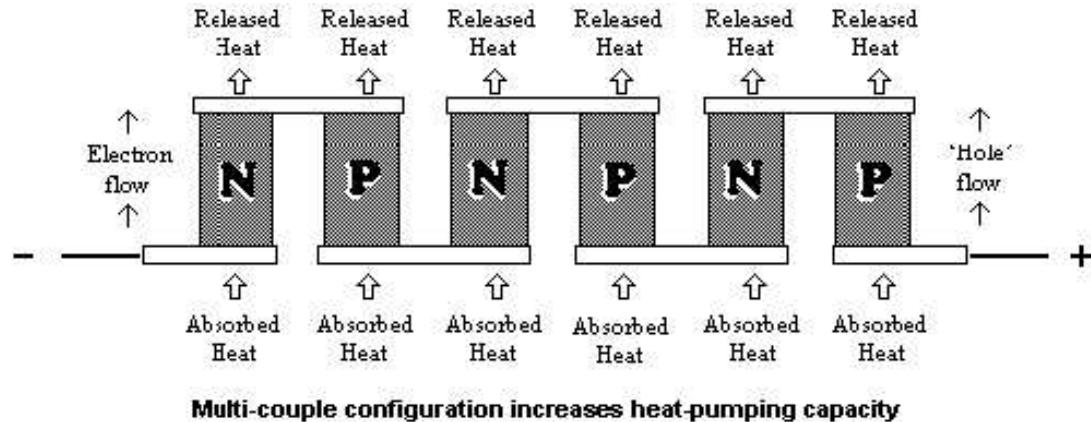


Contact heating

Thermal shortcut

Thermally parallel, electrically in series

Thermoelectric convertor -basic data

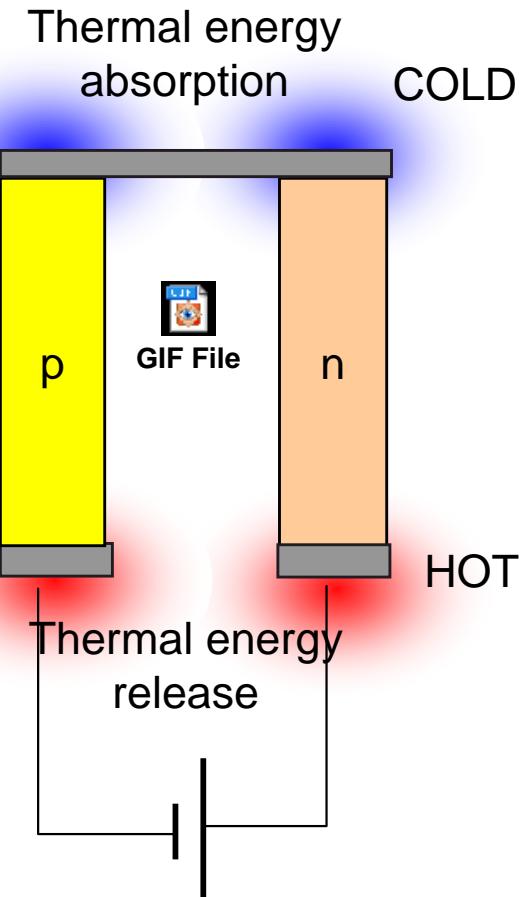


High voltage - low current

Thermoelectric couple- key element of the thermal to electrical energy conversion

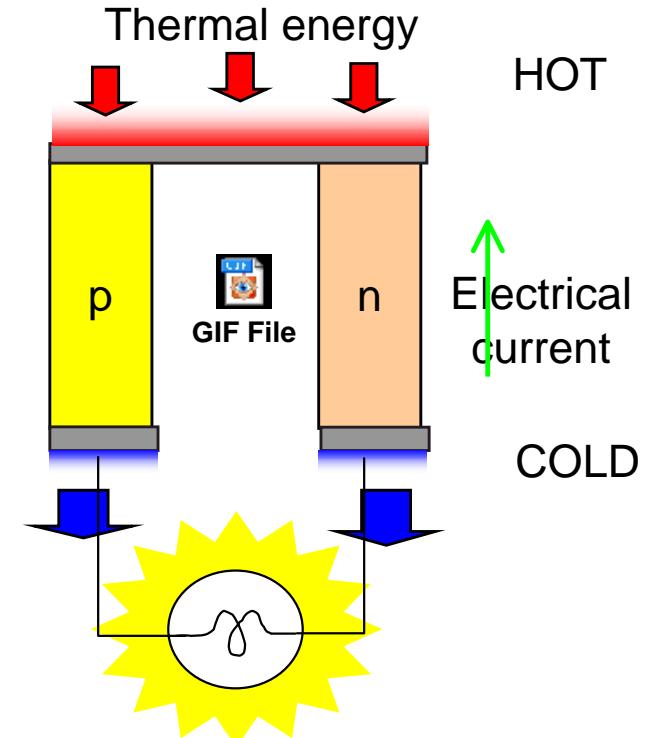
PELTIER (1834)

COOLING



SEEBECK (1821)

Electricity generation

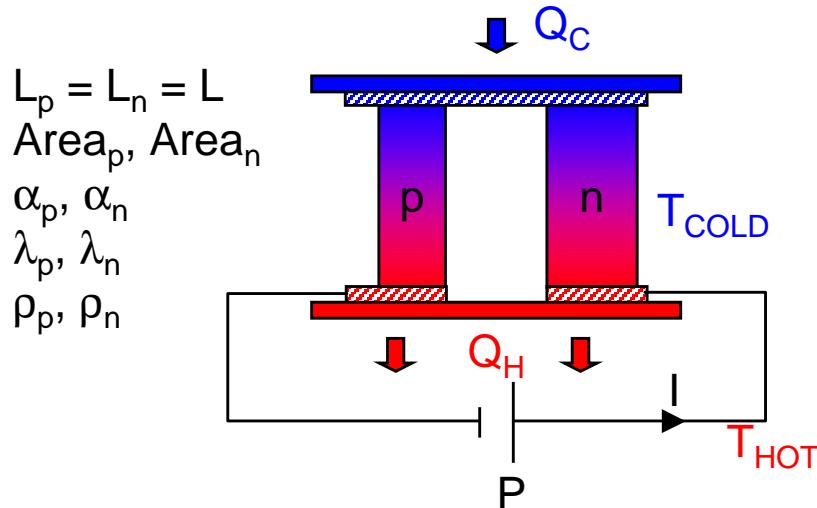


Thermoelectricity

direct conversion of heat into electricity
&
vice versa
Uses
semiconductors,
semimetals,
thermoelectric
alloys, ceramics,
oxides,...

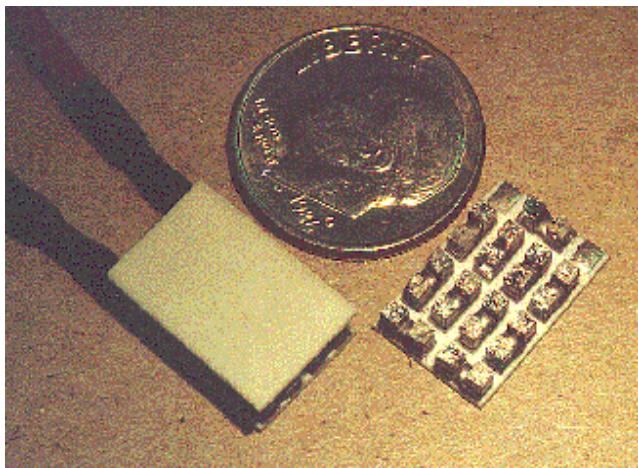
Mathematical description of thermoelectric unicouple ideal energy ballance

Cooling

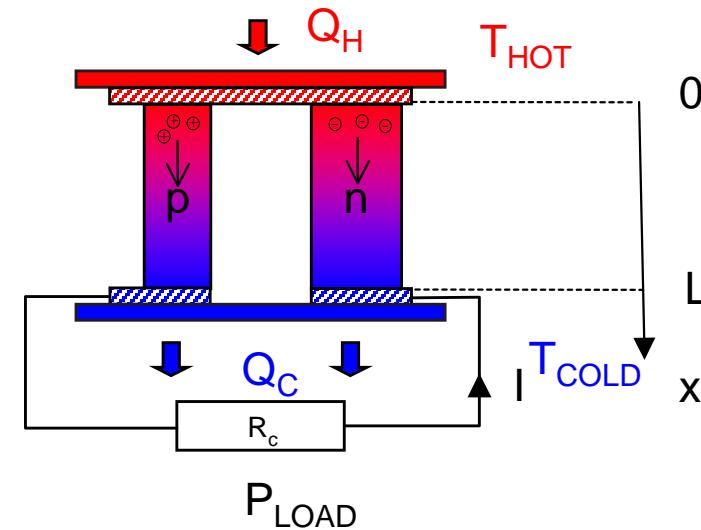


$$P = Q_C + Q_H$$

$$C.O.P. = \frac{Q_H}{P}$$



Energy Generation



$$Q_H = P_{LOAD} + Q_C$$

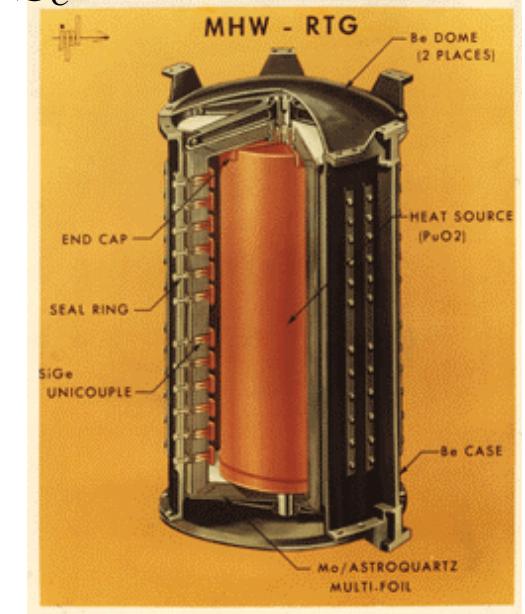
$$\eta = \frac{P_{LOAD}}{Q_H}$$

Commercial Thermoelectric Modules

$$\Delta T = 72\text{C}$$

- Cooling density $< 10\text{W/cm}^2$
- Efficiency 6-8% of Carnot

Thermoelectric modules are used by NASA to power satellites in space



Mathematical description of thermoelectric unicouple ideal energy ballance

Cooling

$$C.O.P. = \frac{Q_C}{P} = \frac{-\alpha T_c I - K\Delta T - \frac{1}{2} R I^2}{R I^2 - \alpha \Delta T I}$$

Maximum C.O.P. $\left(\frac{\partial C.O.P.}{\partial I} \right) = 0$



$$(C.O.P.)_{\max} = \underbrace{\frac{T_c}{T_H - T_c}}_{\text{Carnot}} \frac{\sqrt{1+ZT} - \frac{T_H}{T_c}}{\sqrt{1+ZT} + 1}$$

T : average temperature

Z , P_f, s: figure of merit, power factor, compatibility factor

When different materials or large ΔT are used
(which is actually a general case) the **thermoelectric compatibility** in T and material must also be considered

Generator

$$\eta = \frac{P_{LOAD}}{Q_H} = \frac{R_{LOAD} I^2}{K\Delta T - \alpha T_H I - \frac{1}{2} R I^2}$$

Maximum η : $\left(\frac{\partial \eta}{\partial R_c} \right) = 0$



$$\eta_{\max} = \underbrace{\frac{T_H - T_c}{T_H}}_{\text{Carnot}} \frac{\sqrt{1+ZT} - 1}{\sqrt{1+ZT} + \frac{T_H}{T_c}}$$

$$Z = \frac{\alpha^2}{\rho \lambda} = \frac{P_f}{\lambda}$$

$$s = \frac{\sqrt{1+ZT} - 1}{\alpha T}$$

Applications of P-N couple – ideal matching of properties

Mathematical description of thermoelectric unicouple efficiency

Cooling

$$C.O.P. = \frac{Q_f}{P} = \frac{\alpha_{pn} T_C I - K\Delta T - \frac{1}{2} R I^2}{R I^2 - \alpha \Delta T I}$$

$$\frac{Area_p}{Area_n} = \sqrt{\frac{\rho_p \lambda_n}{\rho_n \lambda_p}}$$

$$(C.O.P.)_{\max} = \frac{T_C}{T_H - T_C} \frac{\sqrt{1 + Z_{np} T} - \frac{T_H}{T_C}}{\sqrt{1 + Z_{np} T} + 1}$$

 Carnot

Electricity Generation

$$\eta = \frac{P_{LOAD}}{Q_H} = \frac{R_c I^2}{K\Delta T + \alpha_{pn} T_H I - \frac{1}{2} R I^2}$$

$$(\eta)_{\max} = \underbrace{\frac{T_H - T_C}{T_H}}_{\text{Carnot}} \frac{\frac{\sqrt{1 + Z_{np} T} - 1}{\sqrt{1 + Z_{np} T} + \frac{T_H}{T_C}}}{\frac{T_H}{T_C}}$$

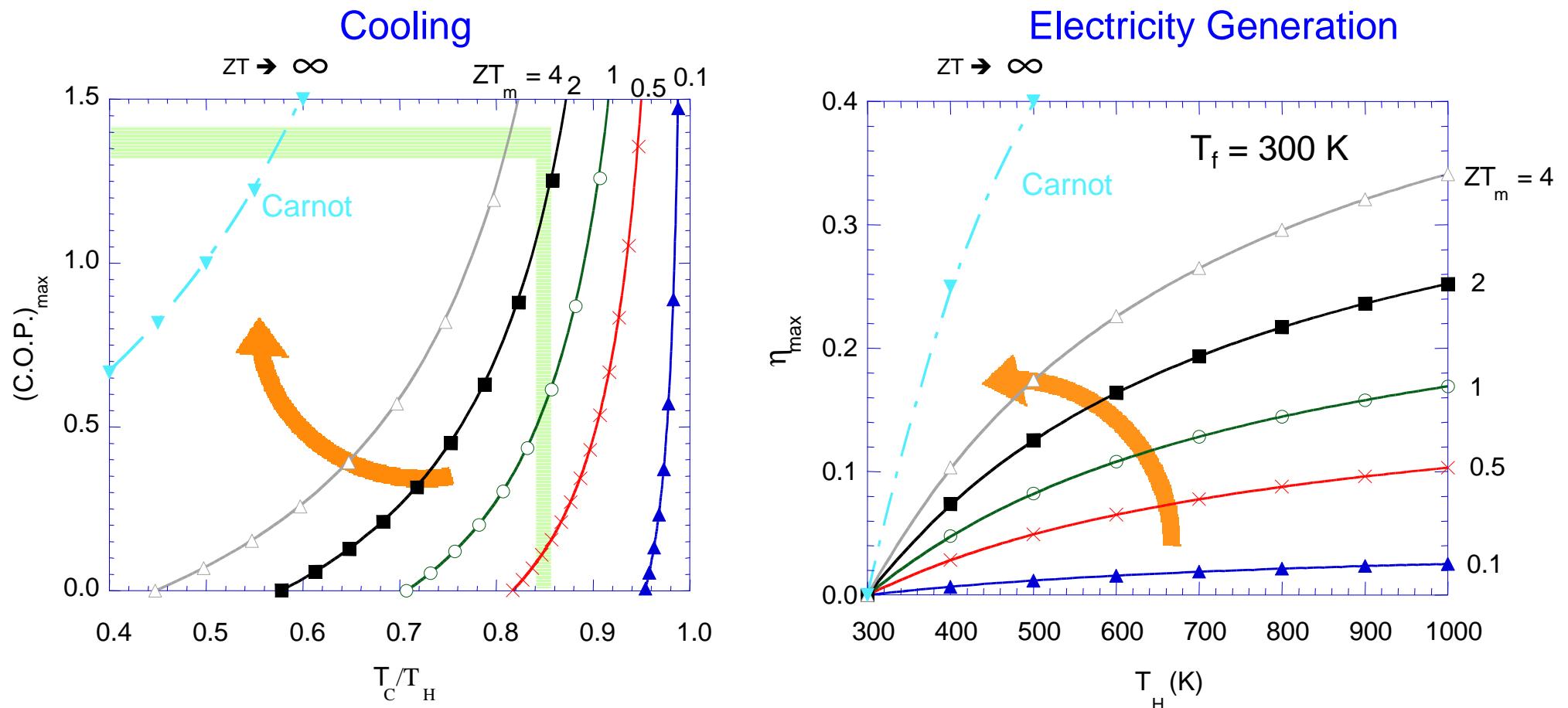
 Carnot

Factor of Merite of the P-N couple Z_{np}

$$Z_{np} = \frac{(\alpha_p - \alpha_n)^2}{[(\rho_p \lambda_p)^{1/2} + (\rho_n \lambda_n)^{1/2}]} \approx \frac{Z_n + Z_p}{2}$$

!! IF close properties !!

Graphical description of TE Performance



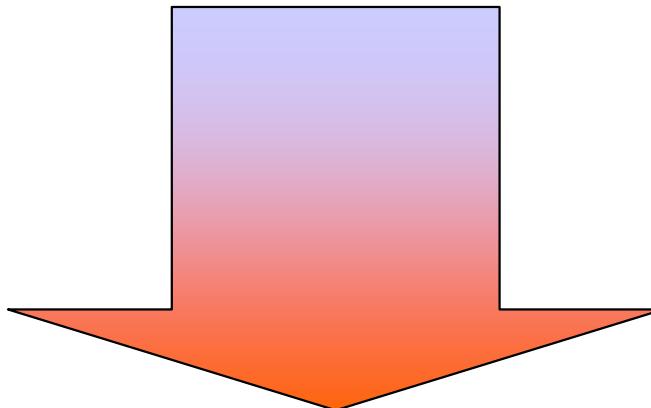
High performance $\rightarrow ZT$ high

Material criteria : ZT (factor of merit) high

Prerequisites for good thermoelectric materials

- 1. Semiconductor
- 2. Low carrier concentration
- 3. High Carrier Mobility
- 4. Low Thermal conductivity

- 1. Right band gap
- 2. Bad thermal conductor
- 3. Good electronic conductor
- 4. Scatter lattice vibration



MATERIAL